



DECLARATION

As the below named inventors, we hereby declare that:

Our residences, post office addresses, and citizenships are as stated below.

We believe we are the original, first, and joint inventors of the subject matter which is claimed and for which a patent is sought on the invention entitled: **Hybrid Solid State/Electrochemical Photoelectrode for Hydrogen Production**, the specification of which is was filed on **August 25, 2003**, and issued application number **10/647,409**.

We hereby state that we have reviewed and understand the contents of the above identified specification, including the claims.

We acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. § 1.56.

We hereby claim the benefit under Title 35, United States Code, § 119(e) of the United States provisional application number **60/406,223**, filed on **August 26, 2002**.

We hereby claim foreign priority benefits under Title 35, United States Code, § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

PRIOR FOREIGN APPLICATION(S)

(Number)	(Country)	(Date filed)
NONE		

We hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, we acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56(a), regarding events which occurred between the filing date of the prior application and the national or PCT International filing date of this application:

(Application Serial No.)	(Filing Date)	(Status)
NONE		

We hereby direct that all correspondence and telephone calls be addressed to **CUSTOMER NO. 25397**, Gary R. Maze, Duane Morris LLP, 3200 South West Freeway, Suite 3150, Houston, Texas 77027, 713.402.3900.

We hereby declare that all statements made herein of our own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

FULL NAME AND ADDRESS OF FIRST INVENTOR:

Name:	Eric L. Miller
Residence:	3029 Lowrey Avenue #L2220 Honolulu, Hawaii 96822
Post Office Address:	same
Citizenship:	United States

6/7/04
Date

E. L. Miller
Inventor's signature

FULL NAME AND ADDRESS OF SECOND INVENTOR:

Name:	Richard E. Rocheleau
Residence:	344 Awini Place Honolulu, Hawaii 96825
Post Office Address:	same
Citizenship:	United States

6/2/04
Date

Richard E. Rocheleau
Inventor's signature



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	Eric L. Miller, et al.	§	
		§	Group Art Unit:
Serial No:	10/647,409	§	
		§	Examiner:
Filed:	08/25/2003	§	
		§	Atty. Docket: D9180-9
For:	Hybrid Solid State/ Electrochemical Photoelectrode for Hydrogen Production	§	
		§	
		§	
		§	

POWER OF ATTORNEY BY ASSIGNEE OF ENTIRE INTEREST

As assignee of record of the entire interest of the above-identified application, the following attorneys are hereby appointed to prosecute and transact all business in the Patent and Trademark Office connected therewith.

CUSTOMER NO. 25397

Richard T. Redano	32,292
Gary R. Maze	42,851
Rudolph J. Szabados	53,664

Please send all correspondence to Gary R. Maze, Duane Morris LLP, 3200 Southwest Freeway, Suite 3150, Houston, Texas 77027. Please direct all phone calls to Gary R. Maze at 713.402.3900.

University of Hawaii

May 27, 2004
Date

Richard F. Cox, Jr.
By: Richard F. Cox, Jr.
Title: Director, Office of Technology
Transfer and Economic Development